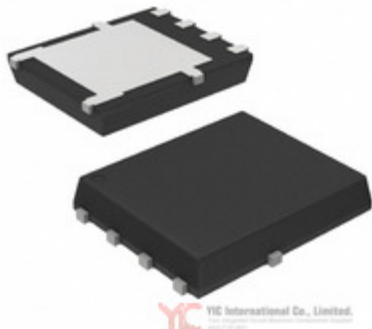

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	Hersteller-Teilenummer: NVMF55C638NLWFT1G
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: 60V 3.0 MOHM T6 S08FL SIN
	Datenblätter:  NVMF55C638NLWFT1G.pdf
	RoHs Status:
	Lagerzustand: New original, Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

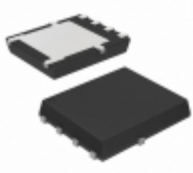
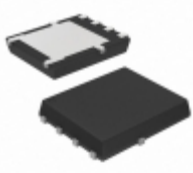
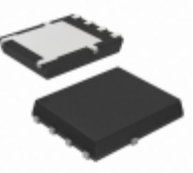
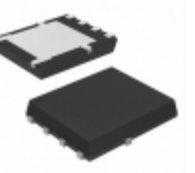
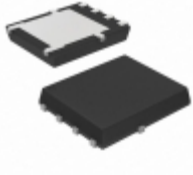
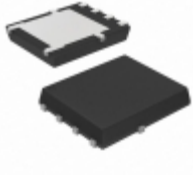
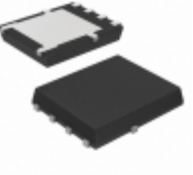
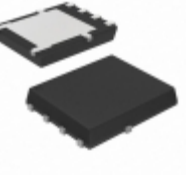
Spezifikationen

Teilenummer	NVMF55C638NLWFT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	60V 3.0 MOHM T6 S08FL SIN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	Require For Quote & Check Stock
VGS (th) (Max) @ Id	2V @ 250µA
Vgs (Max)	±20V
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	5-DFN (5x6) (8-SOFL)
Serie	Automotive, AEC-Q101
Rds On (Max) @ Id, Vgs	3 mOhm @ 50A, 10V
Verlustleistung (max)	4W (Ta), 100W (Tc)
Verpackung / Gehäuse	8-PowerTDFN, 5 Leads
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Hersteller Standard Vorlaufzeit	44 Weeks
Bleifreier Status	Lead free
Eingabekapazität (Ciss) (Max) @ Vds	2880pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	40.7nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Drain-Source-Spannung (Vdss)	60V
detaillierte Beschreibung	N-Channel 60V 26A (Ta), 133A (Tc) 4W (Ta), 100W (Tc)
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	26A (Ta), 133A (Tc)

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Sie können auch interessiert

<p>sein:</p>  <p>NVMF55C638NLT1G AMI Semiconductor / ON Semiconductor 60V 3.0 MOHM T6 S08FL SIN</p>	 <p>NVMF55C628NLWFAFT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 28A 150A 5DFN</p>	 <p>NVMF55C628NLWFT1G ON Semiconductor MOSFET N-CH 60V S08FL</p>	 <p>NVMF55C645NLAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22A 100A 5DFN</p>
 <p>NVMF55C645NLT3G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V DFN5</p>	 <p>NVMF55C645NLT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22A 100A 5DFN</p>	 <p>NVMF55C628NLWFAFT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 28A 150A 5DFN</p>	 <p>NVMF55C628NLWFT3G ON Semiconductor MOSFET N-CH 60V S08FL</p>

Verwandtes Hot-Keyword

Mehr

NVMF55C638NLWFT1G AMI Semiconductor / ON Semiconductor	NVMF55C638NLWFT1G Datenblatt	NVMF55C638NLWFT1G-Datenblätter	NVMF55C638NLWFT1G PDF	AMI Semiconductor / ON Semiconductor NVMF55C638NLWFT1G
NVMF55C638NLWFT1G Electronic	NVMF55C638NLWFT1G-Komponenten	NVMF55C638NLWFT1G-Verteiler	NVMF55C638NLWFT1G-Bild	NVMF55C638NLWFT1G-Teil
NVMF55C638NLWFT1G Preis	NVMF55C638NLWFT1G Hersteller	NVMF55C638NLWFT1G Bild	NVMF55C638NLWFT1G Aktie	NVMF55C638NLWFT1G Inventar
NVMF55C638NLWFT1G Neu	NVMF55C638NLWFT1G Original	NVMF55C638NLWFT1G garantiert	NVMF55C638NLWFT1G RFQ	NVMF55C638NLWFT1G Online bestellen

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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